# DAN222, NSVDAN222

# Common Cathode Silicon Dual Switching Diode

This Common Cathode Silicon Epitaxial Planar Dual Diode is designed for use in ultra high speed switching applications. This device is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications, where board space is at a premium.

#### Features

- Fast t<sub>rr</sub>
- Low C<sub>D</sub>
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** (T<sub>A</sub> = $25^{\circ}C$ )

Rating	Symbol	Value	Unit	
Reverse Voltage	V <sub>R</sub>	80	Vdc	
Peak Reverse Voltage	V <sub>RM</sub>	80	Vdc	
Forward Current	١ <sub>F</sub>	100	mAdc	
Peak Forward Current	I <sub>FM</sub>	300	mAdc	
Peak Forward Surge Current (Note 1)	I <sub>FSM</sub>	2.0	Adc	

#### THERMAL CHARACTERISTICS

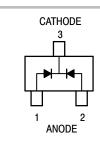
Characteristic	Symbol	Мах	Unit
Power Dissipation	PD	150	mW
Junction Temperature	TJ	150	°C/W
Storage Temperature Range	T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1.  $t = 1 \ \mu S$ 

ON

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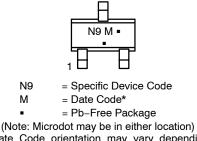
#### http://onsemi.com





SC-75/SOT-416 CASE 463 STYLE 3

#### MARKING DIAGRAM



\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
DAN222G	SC–75 (Pb–Free)	3000 / Tape & Reel
DAN222T1G	SC–75 (Pb–Free)	3000 / Tape & Reel
NSVDAN222T1G	SC–75 (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## DAN222, NSVDAN222

Characteristic	Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Current	۱ <sub>R</sub>	V <sub>R</sub> = 70 V	-	0.1	μAdc
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 100 mA	-	1.2	Vdc
Reverse Breakdown Voltage	V <sub>R</sub>	I <sub>R</sub> = 100 μA	80	-	Vdc
Diode Capacitance	CD	V <sub>R</sub> = 6.0 V, f = 1.0 MHz	-	3.5	pF
Reverse Recovery Time	t <sub>rr</sub> (Note 2)	$I_F$ = 5.0 mA, $V_R$ = 6.0 V, $R_L$ = 100 $\Omega,I_{rr}$ = 0.1 $I_R$	-	4.0	ns

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ )

2. t<sub>rr</sub> Test Circuit on following page.

## **TYPICAL ELECTRICAL CHARACTERISTICS**

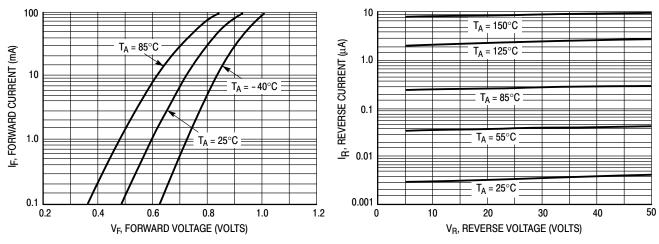
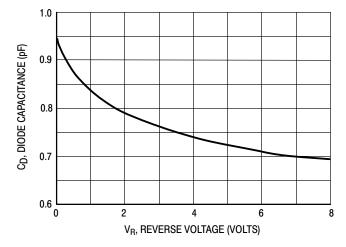


Figure 1. Forward Voltage

Figure 2. Reverse Current





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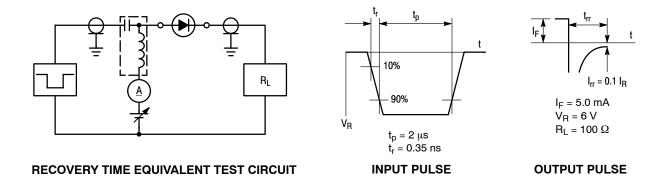


Figure 4. Reverse Recovery Time Test Circuit for the DAN222





\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

1.000

0.039

SCALE 10:1

mm

inches

0.508

0.020

 
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 DESCRIPTION:
 SC-75/SOT-416
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